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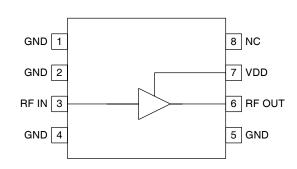


RF2304 GENERAL PURPOSE LOW-NOISE AMPLIFIER

RoHS Compliant & Pb-Free Product Package Style: SOIC-8

Features

- Single 2.7V to 6.0V Supply
- 6dBm Output Power
- 8dB Small Signal Gain at 900MHz
- 1.8dB Noise Figure at 900MHz
- Low DC Current Consumption of 5 mA
- 300MHz to 2500MHz Operation



Applications

- Receive or Transmit Low-Noise Amplifiers
- FDD and TDD Communication Systems
- Commercial and Consumer Systems
- Portable Battery Powered Equipment
- Wireless LAN
- ISM Band Applications

Functional Block Diagram

Product Description

The RF2304 is a low-noise small-signal amplifier. The device is manufactured on a low-cost Gallium Arsenide MESFET process, and has been designed for use as a gain block in high-end communication systems operating from less than 300MHz to above 2.5GHz. With +6dBm output power, it may also be used as a driver in transmitter applications, or in highly linear receivers. The device is packaged in an 8-lead plastic package and is self-contained, requiring just an inductor and block-ing capacitors to operate. The +6dBm output power, combined with the 1.8dB noise figure at 900MHz allows excellent dynamic range for a variety of receive and transmit applications.

Ordering Information

RF2304General Purpose Low-Noise AmplifierRF2304PCBA-41XFully Assembled Evaluation Board

Optimum Technology Matching® Applied

GaAs HBT	□ SiGe BiCMOS	🗌 GaAs pHEMT	🗌 GaN
GaAs MESFET	Si BiCMOS	🗌 Si CMOS	
🗌 InGaP HBT	SiGe HBT	🗌 Si BJT	

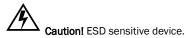
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RF2304



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{DD})	-0.5 to +6.5	V _{DC}
DC Current	40	mA
Input RF Power	+10	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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Dovomotor	Specification		Unit	O and it is n	
Parameter	Parameter Min. Typ. Max.	Onit	Condition		
Operating Range					
Overall Frequency Range	300		2500	MHz	
Supply Voltage	2.7		6.0	V	
Operating Current (I _{CC})		8.4		mA	V _{CC} =3V, Temp=27°C
	7	11	26	mA	V _{CC} =5V, Temp=27°C
Operating Ambient Temperature	-40		+85	°C	
3V Performance					
Gain		11.7		dB	Freq=300 MHz, V _{CC} =3V, Temp=27 °C
Gain		8.5		dB	Freq=900MHz, V _{CC} =3V, Temp=27°C
Noise Figure		1.9		dB	
Input IP3		+6.9		dBm	
OP1dB		+7.5		dBm	
Gain		9.2		dB	Freq=1950MHz, V _{CC} =3V, Temp=27 °C
Noise Figure		1.7		dB	
Input IP3		+8.6		dBm	
OP1dB		+6.9		dBm	
Gain		8.2		dB	Freq=2450MHz, V _{CC} =3V, Temp=27 °C
Noise Figure		1.7		dB	
Input IP3		+10.5		dBm	
OP1dB		+7.5		dBm	
5V Performance					
Gain		12.5		dB	Freq=300MHz, V _{CC} =5V, Temp=27 °C
Gain	10	12	14	dB	Freq=900MHz, V _{CC} =5V, Temp=27 °C
Noise Figure		1.9		dB	
Input IP3		+8.4		dBm	
OP1dB		+8.7		dBm	
Gain		9.8		dB	Freq=1950MHz, V _{CC} =5V, Temp=27 °C
Noise Figure		1.9		dB	
Input IP3		+10.0		dBm	
OP1dB		+8		dBm	
Gain	6	8	11	dB	Freq=2450MHz, V _{CC} =5V, Temp=27°C
Noise Figure		1.6		dB	
Input IP3		+8.0		dBm	
OP1dB		+6		dBm	

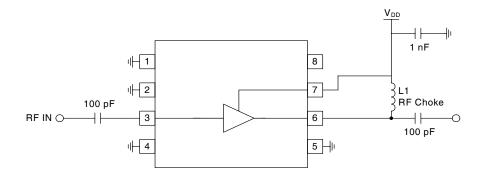


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Pin	Function	Description	Interface Schematic
1	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
2	GND	Same as pin 1.	
3	RF IN	DC coupled RF input. A broadband impedance match is produced by inter- nal shunt resistive feedback. The DC level is approximately 200mV. If a DC path exists in the connected circuitry, an external DC-blocking capacitor is required to properly maintain the DC operating point.	
4	GND	Same as pin 1.	
5	GND	Same as pin 1.	
6	RF OUT	RF output. A broadband impedance match is produced by internal shunt resistive feedback. The DC connection to the power supply is provided through an external chip inductor having greater than 150Ω reactance at the operating frequency. An external DC-blocking capacitor is required if the following circuitry is not DC-blocked.	
7	VDD2	Bias control connection. This pin is normally connected to the power supply, but can be used to switch the amplifier on and off by switching between power supply voltage and ground. This pin sinks approximately $600\mu\text{A}$ when connected to V_{DD} , and sources less than $10\mu\text{A}$ when grounded.	
8	NC	No connection.	

Application Schematic

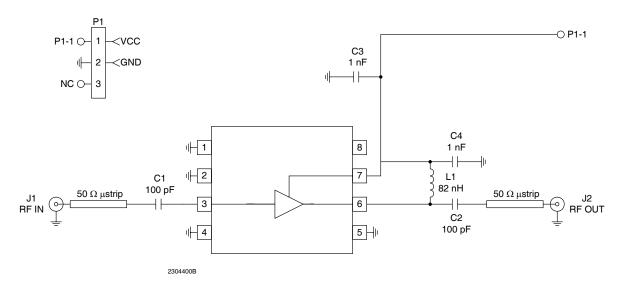




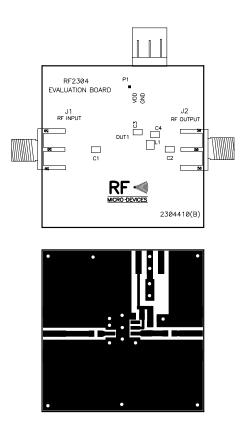


Evaluation Board Schematic

(Download Bill of Materials from www.rfmd.com.)

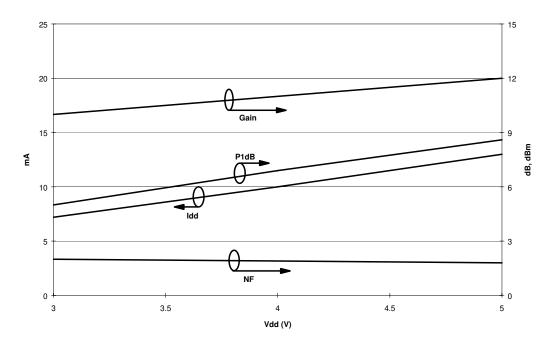


Evaluation Board Layout 1.43" x 1.43"



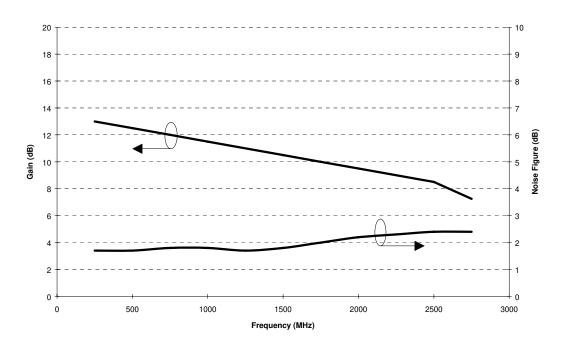






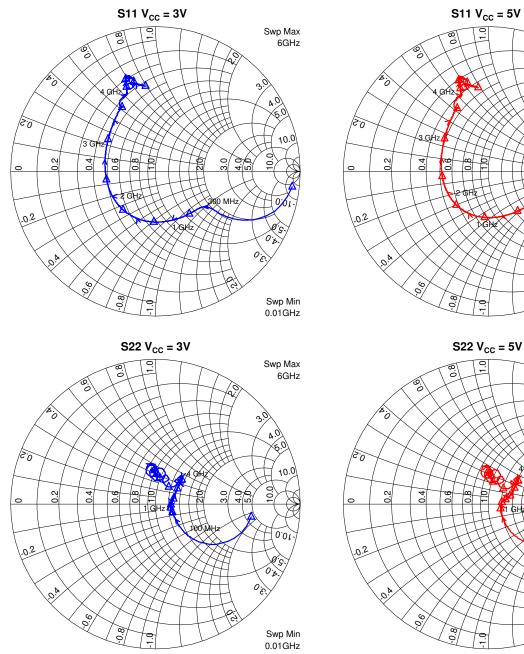
Typical Characteristics - f=900 MHz

Typical Characteristics - V_{DD}=5.0V

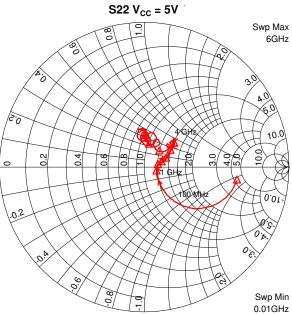


RF2304

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Swp Max 00 . 6GHz 4.0 দ 10.0 0 0 ίðο MHz 0.8 Swp Min 0.01GHz



S-Parameter Conditions:

All plots are taken at ambient temperature=25°C.

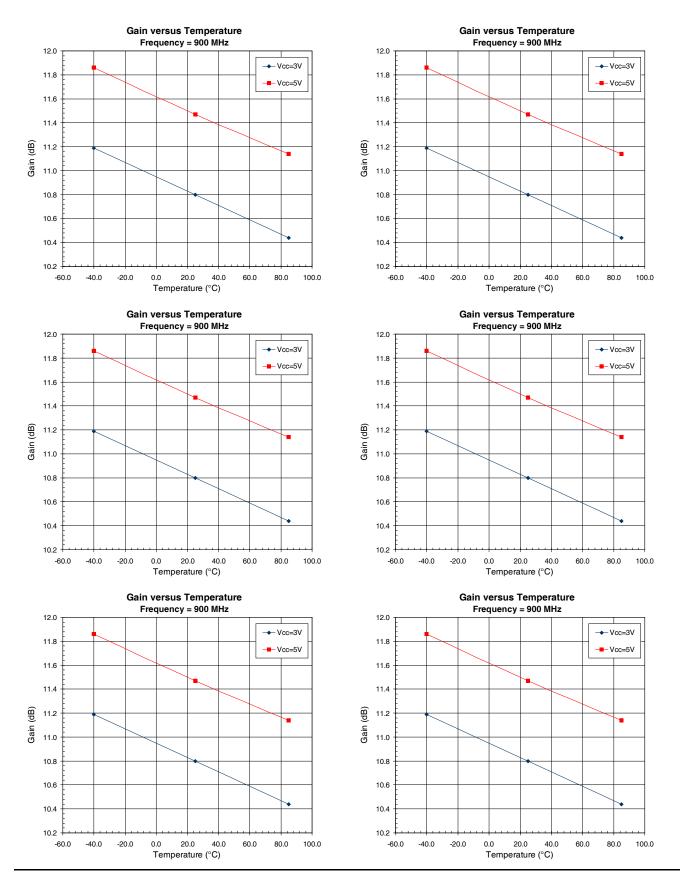
NOTE:

All S11 and S22 plots shown were taken from an RF2304 evaluation board with external input and output tuning components removed and the reference points at the RF IN and RF OUT pins.





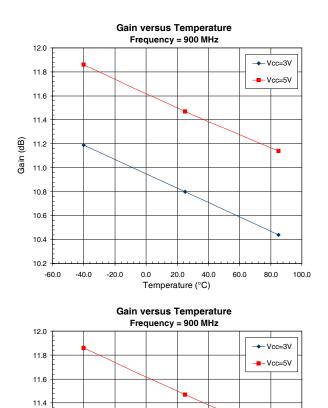
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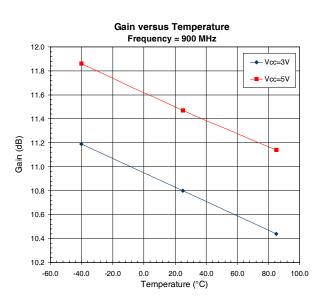


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(qB) 11.2 11.0

11.0 10.8 10.6 10.4 10.2 -60.0

-40.0

-20.0

0.0

20.0

Temperature (°C)

40.0

60.0

80.0

100.0